

EXTENDED ABSTRACT

Synthesis and Characterization of some Rare Earth Metals doped Bismuth Copper Titanate Ceramics



Name of Student: DINESH PRAJAPATI

Roll No.:19051002

Degree for which submitted: DOCTOR OF PHILOSOPHY

Name of Department/School: CHEMISTRY

Signature of the Supervisor

(Prof. K.D. Mandal)

Materials science and technology have perpetually occupied a central role in the advancement of any progressive society. The evolution of electro-ceramic materials has notably expanded their potential for diverse applications, spanning optical, structural, environmental remediation, and sensor technologies. Among these, electro-ceramics featuring perovskite oxides/structures ABO_3 have emerged as a significant class of compounds, due to their numerous incredibly interesting chemical, mechanical, thermal, physical, magnetic, and optical properties. A variety of partial substitutions on the A- or B-sites, as well as simultaneous substitutions, can alter the characteristics of the perovskite. Substitutions can be expressed as $A_{1-x}A'_xBO_3$, $AB_{1-x}B'_xO_3$, and $A_{1-x}A'_xB_{1-x}B'_xO_3$, respectively. These substitutions can be heterovalent, isovalent, or valence compensated in perovskite oxide. It is well understood that the substituent's valency, radius, and coordination number are significant parameters in determining the location where it occupies in the perovskite oxide with a limited composition range to produce a solid solution. Ceramic materials having a high dielectric constant and good thermal stability have received a lot of interest, primarily for their use in electronic devices such as memory devices, gas sensors, humidity sensors, and capacitors.

Calcium copper titanate (CCTO) has the chemical formula $CaCu_3Ti_4O_{12}$, a novel electroceramic material with a high dielectric permittivity (ϵ') of roughly 100,000 for single crystals and 10,000 for bulk materials at ambient temperature. CCTO exhibits minimal dielectric loss ($\tan \delta \sim 0.15$) across a large frequency range (up to 10^6 Hz) and maintains phase transition stability at temperatures ranging from 100 to 400 K. In 2000, Subramanian et al. discovered that CCTO belongs to the family of $ACu_3Ti_4O_{12}$ ($A = Ca, Sr, Ba, Bi_{2/3}, Y_{2/3}, La_{2/3}$)-type oxide of the pseudo-cubic perovskite-related structure (space group: $Im\bar{3}$) with a lattice parameter of 7.391 Å. CCTO's high ϵ value, which remains constant at temperatures ranging

from 100 to 400 K, makes it suitable for an array of applications. The advancement of technology necessitates a material with a high ϵ value to shrink the size of electronic components, while the efficient performance of these components requires a significantly low $\tan \delta$. Despite CCTO possessing a very large dielectric constant, its main drawback, especially for undoped CCTO and its related materials, is a slightly high dielectric loss at room temperature. Numerous research studies have been reported on CCTO aimed at reducing dielectric loss by modifying its intrinsic and extrinsic behavior through various methods such as different cationic substitutions or doping at various sites of CCTO, synthetic techniques, and processing parameters to create ideal capacitor materials.

$\text{Bi}_{2/3}\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BCTO), a member of the $\text{CaCu}_3\text{Ti}_4\text{O}_{12}$ (CCTO) family, exhibits a similar structure. It has been synthesized using various methods and has shown a very high dielectric constant. However, a high tangent loss was also observed at room temperature, rendering it unsuitable for practical applications. To address this issue, we have chosen the ion doping or substitution method to reduce the tangent loss of the ceramic material. We have reported here the results of our investigation on a class of compounds having perovskite-related structure. These have dielectric properties very different from those of ferroelectrics or relaxors. Their high dielectric constant shows only a small dependence on temperature.

In the current study, various rare earth elements such as neodymium (Nd), samarium (Sm), gadolinium (Gd), and dysprosium (Dy) doped Bismuth Copper Titanate ($\text{Bi}_{2/3}\text{Cu}_3\text{Ti}_4\text{O}_{12}$) (BCTO) ceramic were produced using a well-known semi-wet approach that avoided the need of expensive titanium isopropoxide $\text{Ti}(\text{OR})_4$. In this process, metal nitrates and acetates of Bi, Cu, Nd, Sm, Gd, and Dy were combined with TiO_2 powder. These materials were synthesized using this approach at lower temperatures and in a shorter time. All synthesized materials

were characterized using multiple physicochemical approaches to describe microstructure, crystal structure, particle size and shape, elemental analysis, surface roughness, dielectrics, and electrical characteristics in detail.

The present work aims to synthesize Nd, Sm, Gd, and Dy-doped BCTO ceramics and describe the crystal structure, microstructure, elemental analysis, surface roughness, dielectric and electrical behavior of the following systems:

- $\text{Bi}_{(2/3-x)}\text{Nd}_x\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BNCTO, $x=0.05, 0.10$ and 0.20)
- $\text{Bi}_{(2/3-x)}\text{Sm}_x\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BSCTO, $x=0.05, 0.10,$ and 0.20)
- $\text{Bi}_{(2/3-x)}\text{Gd}_x\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BGCTO, $x=0.05, 0.10$ and 0.20)
- $\text{Bi}_{(2/3-x)}\text{Dy}_x\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BDCTO, $x=0.05, 0.10$ and 0.20)

To the best of our knowledge, there has been no report in the literature on these substituted materials synthesized using this unique approach. A brief description of the research work presented in the thesis divided into seven chapters has been given as follows:

Chapter 1 This chapter contains a general introduction to the subject describing briefly the technical investigation reported in the field of perovskite oxides complex perovskite oxides and ceramic materials. This chapter includes the effect of various substitutions such as heterovalent, isovalent, and valence compensated substitutions on the dielectric and electrical properties of the materials, and the purpose of the thesis is also mentioned in this chapter.

Chapter 2 described the experimental procedure used for the preparation and characterization of the complex perovskite oxides. The semi-wet route was used for the preparation of materials with the help of a flow chart. Powder X-ray diffraction (XRD) and retravel refinement have been used to determine the crystallite size and phase formation of

materials. Transmission electron microscope (TEM) coupled with selected area electron diffraction pattern (SAED) have been used for the determination of particle size and crystalline behavior of the material respectively. Scanning electron microscope (SEM) and energy dispersive X-ray spectroscopy (EDX) analysis have been used to examine the surface microstructure and elemental composition of the samples. Surface roughness and average grain size of the materials can be measured by using atomic force microscopy (AFM) techniques. X-ray photoemission spectroscopy (XPS) was used to analyze the valence state of elements present in the ceramics. Using a high-performance frequency LCR meter (E4980A/AL, Keysight, Malaysia) with a frequency range of 20 Hz to 2 MHz, dielectric and electrical measurements were carried out at various temperatures (303 K-503 K). Dielectric properties and electrical properties which are characteristic of all ceramics were also measured with the help of LCR meter with the variation of temperature and frequency (100 Hz-5 MHz).

Chapter 3 The detailed synthesis, characterization, and application of $\text{Bi}_{(2/3-x)}\text{Nd}_x\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BNCTO) ceramic with composition ($x = 0.05, 0.1, \text{ and } 0.2$) prepared by semi-wet route and sintered at 1173 K for 8 h were described in this chapter. X-ray diffraction (XRD) pattern emphasized the single-phase formation up to $x = 0.05-0.1$ without any signature of secondary phase, however small amount of secondary phase of rutile phase of TiO_2 was also deducted by XRD with the composition $x = 0.2$. This impurity phase was also confirmed with the help of Rietveld analysis of XRD data. The average grain size was determined from scanning electron microscope (SEM) of BNCTO ceramics decreases with a rise in composition and are found to be $0.83 \mu\text{m}$, $0.65 \mu\text{m}$, and $0.641 \mu\text{m}$, respectively. The stoichiometry, purity, and the presence of elements (Bi, Cu, Nd, Ti, and O) of synthesized samples were confirmed by EDX studies. AFM analysis shows a reduction in surface root mean square roughness (R_{rms}) as the proportion of Nd^{3+} ions increase, with corresponding

values of 255 nm, 158 nm, and 125 nm, respectively, and average grain size also decreases which validates the SEM result. XPS spectroscopy confirmed the oxidation state of the elements present in the ceramic. Surprisingly, Nd doping can result in an exceptionally low dielectric loss ($\tan \delta$), with a minimum value of 0.05 at 1 kHz and 303 K for BNCTO-0.2. These findings show that Nd doping is more favorable to dielectric characteristics, introducing increased grain boundary resistance, activation energy, and lower conductivity. The detailed temperature and frequency dependence of dielectric properties and conductivity of BNCTO ceramic were disclosed in this chapter

Chapter 4 This chapter describes the dielectric and electrical properties of $\text{Bi}_{(2/3)-x}\text{Sm}_x\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BSCTO) with $x=0.05, 0.1$ and 0.2 . Compositions were synthesized by a low-temperature semi wet route and sintered at 1173 K for 8 h. X-ray powder diffraction analysis unequivocally confirmed the formation of a monophasic BCTO cubic phase without any discernible secondary phases and the crystallite size of the BSCTO ceramic, obtained by X-ray diffraction using Debye Scherrer formula, range from 62 to 81 nm. Rietveld analysis reveals that ceramics have a body centered cubic structure with space group Im-3. Scanning electron microscopy (SEM), energy dispersive X-ray spectroscopy (EDS), atomic force microscope (AFM), and X-photoelectron spectroscopy (XPS) were used to study the surface morphology, elemental compositions, surface roughness, and electronic state, respectively. At room temperature and 1 kHz, the composition ($x = 0.2$) has a dielectric constant of around 152 and a dielectric loss of 0.04, respectively. Impedance characteristics revealed a substantial increase in grain boundary resistance, leading to improved dielectric loss. The AC conductivity of BSCTO ceramics exhibited a frequency-dependent increase satisfying Johncher's power law.

Chapter 5 The effect of Gd doping in $\text{Bi}_{2/3}\text{Cu}_3\text{Ti}_4\text{O}_{12}$ ceramic was described in this chapter. Samples of $\text{Bi}_{(2/3)-x}\text{Gd}_x\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BGCTO, $x=0.05, 0.10$ and 0.20) were synthesized by semi-wet route and sintered at 1173 K for 8 h . Single phase formation with cubic phase of the sintered material was confirmed by X-ray diffraction (XRD) analysis. Rietveld refinement revealed that the material has a BCC structure with space group Im-3 . The particle size and crystalline nature of BGCTO ceramic were confirmed by the TEM analysis and SEAD pattern. Further, particle size was determined with the help of Image J software and found to be $90.85\pm 5\text{ nm}$, $75.35\pm 5\text{ nm}$, and $72.43\pm 5\text{ nm}$, respectively for BGCTO ceramic with composition ($x=0.05, 0.10$, and 0.20). The Scanning electron microscope (SEM) images show that the surface morphology consists of plates and spherical grains and EDX analysis confirmed the presence of Bi, Gd, Cu, Ti, and O with their atomic and weight percentage. The oxidation state of the elements which is present in the BGCTO ceramic was validated by XPS analysis. A detailed discussion of temperature and frequency dependent dielectric constant and dielectric loss, electrical, and impedance studies were widely discussed in this chapter.

Chapter 6 Synthesis of Dysprosium doping at the site of bismuth is discussed in this chapter. $\text{Bi}_{(2/3)-x}\text{Dy}_x\text{Cu}_3\text{Ti}_4\text{O}_{12}$ (BDCTO, $x=0.05, 0.10$ and 0.20) BDCTO ceramic with compositions $x = 0.05, 0.10$, and 0.20 as designated BDCTO-0.05, BDCTO-0.1, and BDCTO-0.2 respectively, were synthesized through semi wet route and at a sintering temperature of 1173 K for 8 h . The X-ray diffraction pattern and Rietveld analysis reveal the occurrence of all the peaks of parent BCTO ceramic which confirm the formation of a single phase on doping of Dy up to composition 0.2 with the fine crystal structure and have space group Im-3 . The particle size of the BDCTO ceramics obtained from the transmission electron microscopy images was found in the ranges of $80\text{--}101\text{ nm}$. The average grain sizes obtained

by SEM of the BDCTO-0.05, BDCTO-0.1, and BDCTO-0.2 ceramics were found to be 123.44 nm, 125.36 nm, and 132.11 nm, respectively. Elemental analysis was performed by EDX that confirmed the presence of all elements in the ceramic with their atomic percentage. The presence of Bi-O, Ti-O, and Ti-O-Ti stretching bands in the ceramic was confirmed by a Fourier transform infrared (FTIR) study. The oxidation state of various ions was studied using X-ray photoelectron spectroscopy. Temperature and frequency dependent dielectric constant, dielectric loss, and conductivity were also extensively studied. Impedance analysis reveals the presence of electrically heterogeneous behavior of the synthesized ceramics.

Chapter 7 describes the summary of the present research work and its future scope.